

# LM111-LM211-LM311

### Voltage Comparators

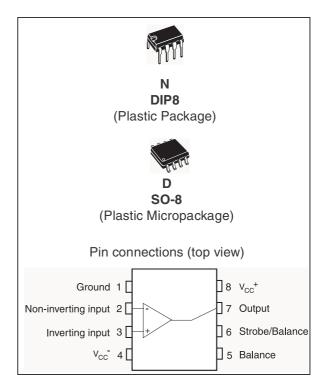
- Maximum input current: 150nA
- Maximum offset current: 20nA
- Differential input voltage range: ±30V
- Power consumption:135mW at ±15V
- Supply voltage: +5V to ±15V
- Output current: 50mA

### Description

The LM111, LM211, LM311 are voltage comparators that have low input currents.

They are also designed to operate over a wide range of supply voltages : from standard  $\pm 15V$  operational amplifier supplies down to the single +5V supply used for IC logic.

Their output is compatible with RTL-DTL and TTL as well as MOS circuits and can switch voltages up to +50V at outputs currents as high as 50mA.



### **Order Codes**

Part Number	Temperature Range	Package	Packing	Marking
LM211N	-40°C, +105°C	DIP8	Tube	LM211N
LM211D/DT	-40 C, +105 C	SO-8	Tube or Tape & Reel	211
LM311N	0°C 170°C	DIP8	Tube	LM311
LM311D/DT	0°C, +70°C	SO-8	Tube or Tape & Reel	311

## 1 Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	36	V
V <sub>id</sub>	Differential Input Voltage	±30	V
V <sub>i</sub>	Input Voltage (1)	±15	V
V <sub>(1-4)</sub>	Ground to Negative Supply Voltage	30	V
V <sub>(7-4)</sub>	Output to Negative Supply Voltage LM111-LM211 LM311	50 40	V
	Output Short-Circuit Duration	10	s
	Voltage at strobe pin	V <sub>CC</sub> <sup>+</sup> -5	V
P <sub>d</sub>	Power Dissipation <sup>(2)</sup> DIP8 SO-8	1250 710	mW
Тj	Junction Temperature	+150	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C

#### Table 1. Key parameters and their absolute maximum ratings

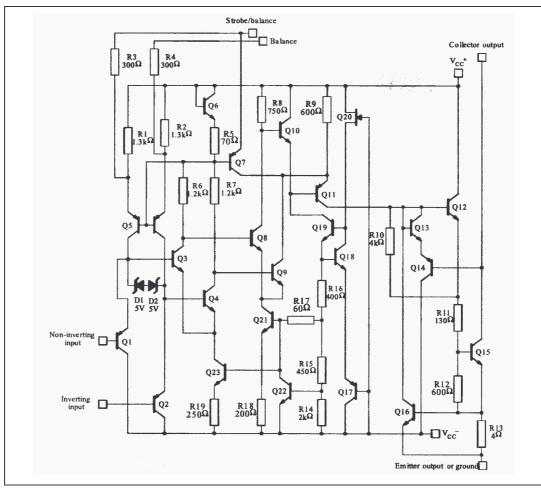
This rating applies for ±15V supplies. The positive input voltage limit is 30V above the negative. The negative input voltage is equal to the negative supply voltage or 30V below the positive supply, whichever is less.

2. Pd is calculated with  $T_{amb}$  = +25°C,  $T_j$  = +150°C and  $R_{thja}$  = 100°C/W for DIP8 package = 175°C/W for SO-8 package

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	5 to ±15	V
T <sub>oper</sub>	Operating Free-Air Temperature range LM111 LM211 LM311	-55 to +125 -40 to +105 0 to +70	°C

#### Table 2. Operating conditions

## 2 Typical Application Schematic



#### Figure 1. Schematic diagram



## **3 Electrical Characteristics**

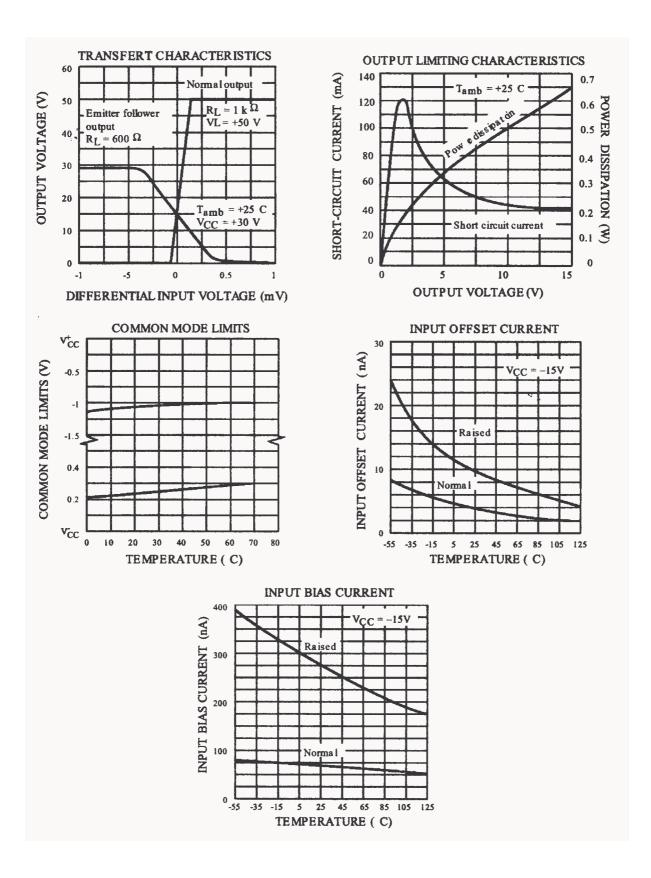
Symbol	Parameter	Conditions	LM111 - LM211			LM311			Unit
			Min.	Тур.	Max.	Min.	Тур.	Max.	
V <sub>io</sub>	Input Offset Voltage <sup>(1)</sup>	$\label{eq:rescaled_response} \begin{split} \textbf{R}_{\textbf{S}} &\leq \textbf{50k} \Omega \\ \textbf{T}_{amb} &= +25^{\circ} \textbf{C} \\ \textbf{T}_{min} &\leq \textbf{T}_{amb} \\ &\leq \textbf{T}_{max} \end{split}$		0.7	3 4		2	7.5 10	mV
I <sub>io</sub>	Input Offset Current see note 1)	$\begin{array}{l} T_{amb} = +25^{\circ}C \\ T_{min} \leq T_{amb} \ \leq T_{max} \end{array}$		4	10 20		6	50 70	nA
I <sub>ib</sub>	Input Bias Current (see note 1)	$T_{amb}$ = +25°C $T_{min} \le T_{amb} \le T_{max}$		60	100 150		100	250 300	nA
A <sub>vd</sub>	Large Signal Voltage Gain		40	200		40	200		V/mV
I <sub>CC</sub> ⁺ I <sub>CC</sub> ⁻	Supply Currents	Positive Negative		5.1 4.1	6 5		5.1 4.1	7.5 5	mA
V <sub>icm</sub>	Input Common Mode Voltage Range	$T_{min} \le T_{amb} \le T_{max}$	-14.5	+13.8 -14.7	+13	-14.5	+13.8 -14.7	+13	V
		$T_{amb}$ = +25°C, $I_0$ = 50mA, $V_i \le -5mV$		0.75	1.5				-
		$T_{amb} = +25$ °C, $I_O = 50$ mA, $V_i \le -10$ mV					0.75	1.5	
V <sub>OL</sub>	Low Level Output Voltage	$ \begin{array}{l} T_{min} \leq T_{amb} \leq T_{max} \\ V_{CC}^+ \geq +4.5V, \ V_{CC}^- = 0 \\ I_O = 8mA, \ V_i \leq -6m \end{array} $		0.23	0.4				V
							0.23	0.4	
		$T_{amb}$ = +25°C Vi ≥ +5mV,Vo = +35V		0.2	10				nA
I <sub>OH</sub>	High Level Output Current	$T_{amb} = +25^{\circ}C$ Vi ≥ +10mV,Vo = +35V					0.2	50	nA
		$\begin{array}{l} T_{min} \leq T_{amb} \leq T_{max} \\ Vi \geq +5mV, Vo = +35V \end{array}$		0.1	0.5				μA
Istrobe	Strobe Current			3			3		mA
t <sub>re</sub>	Response Time (2)			200			200		ns

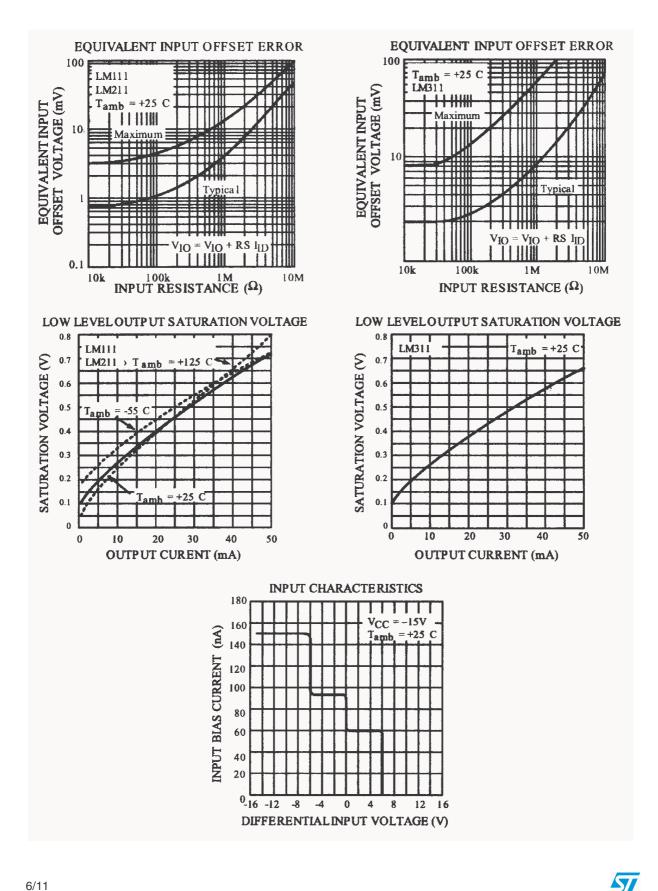
Table 3.	$V_{CC}^+ = \pm 15V, T_{amb}$	= +25°C (unless	otherwise specified)
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 The offset voltage, offset current and bias current specifications apply for any supply voltage from a single +5V supply up to ±15V supplies. The offset voltages and offset currents given are the maximum values required to drive the output down to +1V or up to +14V with a 1mA load current. Thus, these parameters define an error band and take into account the worstcase of voltage gain and input impedance.

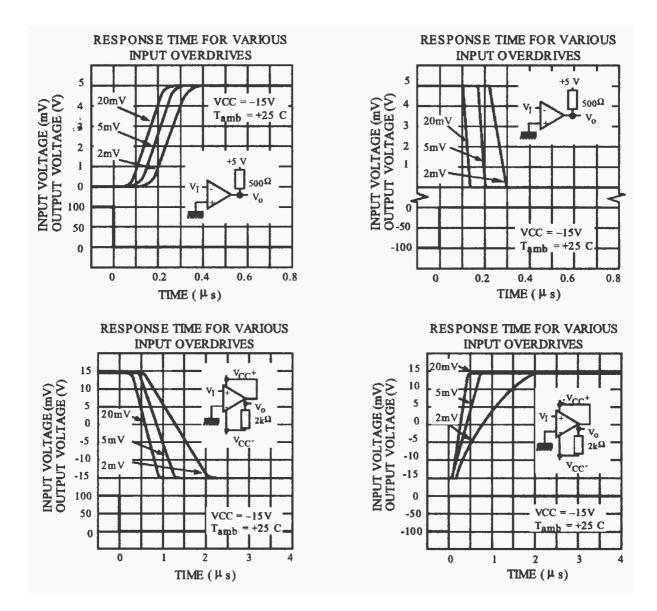
2. The response time specified (see definitions) is for a 100mV input step with 5mV overdrive.





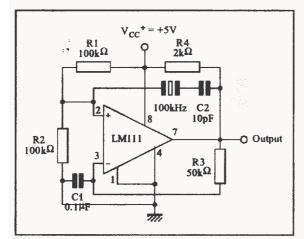


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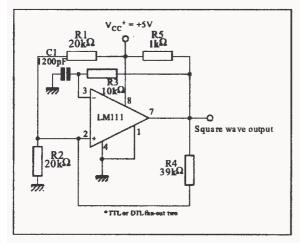


#### **TYPICAL APPLICATIONS**

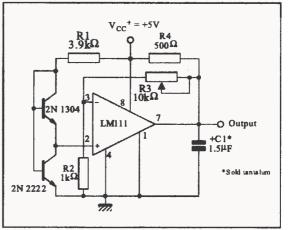
CRYSTAL OSCILLATOR



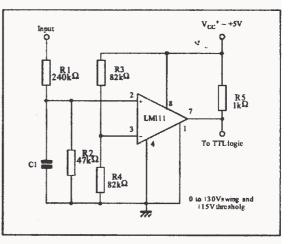
**100KHz FREE RUNNING MULTIVIBRATOR** 



LOW VOLTAGE ADJUSTABLE REFERENCE SUPPLY

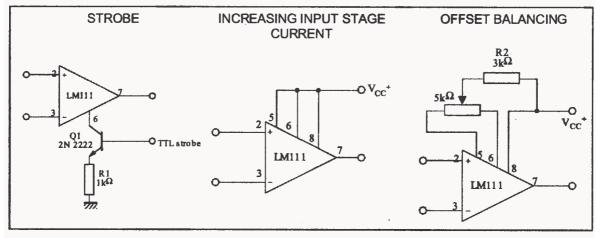


TTL INTERFACE WITH HIGH LEVEL LOGIC



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#### **AUXILIARY CIRCUITS**

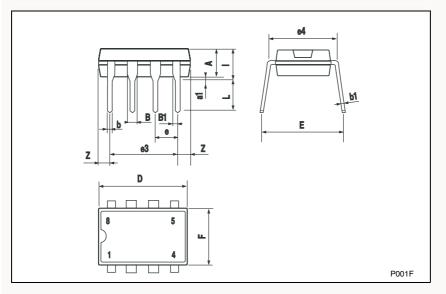


## 4 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

#### 4.1 DIP8 Package

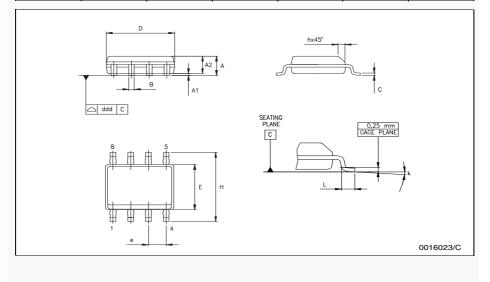
	Plastic DIP-8 MECHANICAL DATA						
	mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А		3.3			0.130		
a1	0.7			0.028			
В	1.39		1.65	0.055		0.065	
B1	0.91		1.04	0.036		0.041	
b		0.5			0.020		
b1	0.38		0.5	0.015		0.020	
D			9.8			0.386	
E		8.8			0.346		
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			7.1			0.280	
I			4.8			0.189	
L		3.3			0.130		
Z	0.44		1.6	0.017		0.063	





## 4.2 SO-8 Package

	SO-8 MECHANICAL DATA							
DIM	1	mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.		
А	1.35		1.75	0.053		0.069		
A1	0.10		0.25	0.04		0.010		
A2	1.10		1.65	0.043		0.065		
В	0.33		0.51	0.013		0.020		
С	0.19		0.25	0.007		0.010		
D	4.80		5.00	0.189		0.197		
E	3.80		4.00	0.150		0.157		
е		1.27			0.050			
Н	5.80		6.20	0.228		0.244		
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
k		g° (max.)						
ddd			0.1			0.04		



## 5 Revision history

#### Table 4.Document revision history

Date	Revision	Changes
June 2002	1	- Initial release.
Jan. 2006	2	<ul> <li>Table 3. on page 4 updated.</li> <li>Formatting changes throughout.</li> </ul>

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